



Chip varistors

ESD/Voltage protection devices

AVR/SGNE series

- AVRM/AVR-M : Standard Type**
 - AVRL : Low Capacitance Type**
 - AVRH : High reliability Type**
 - SGNE : Low Clamp Type**
-

Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

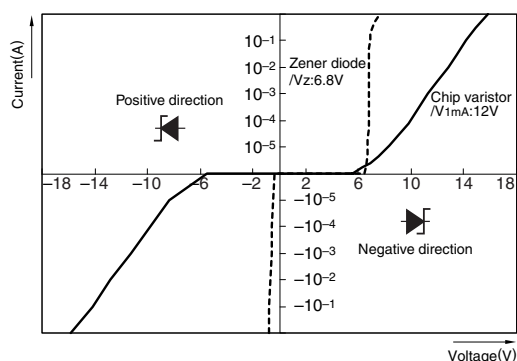
Overview of the AVR/SGNE series

■ CHARACTERISTICS OF CHIP VARISTOR

Varistors are voltage dependent nonlinear resistive elements with a resistance that decreases rapidly when the voltage is over the constant value.

Varistors become zener diode of 2 serial connection and equivalent, and does not have polarity.

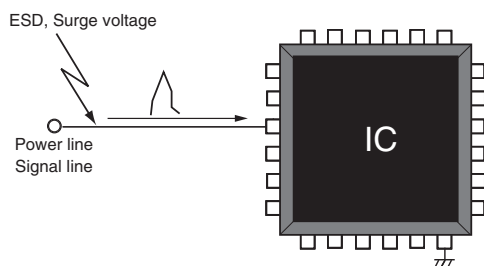
□ CURRENT vs. VOLTAGE CHARACTERISTICS



□ THE EFFECT OF THE VARISTOR

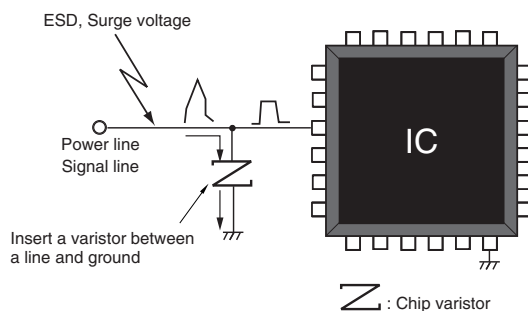
Without varistor

A malfunction and failure of electronic equipment

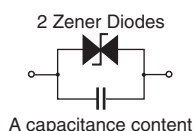


With Varistor

Suppress abnormal voltage by inserting varistor in a circuit



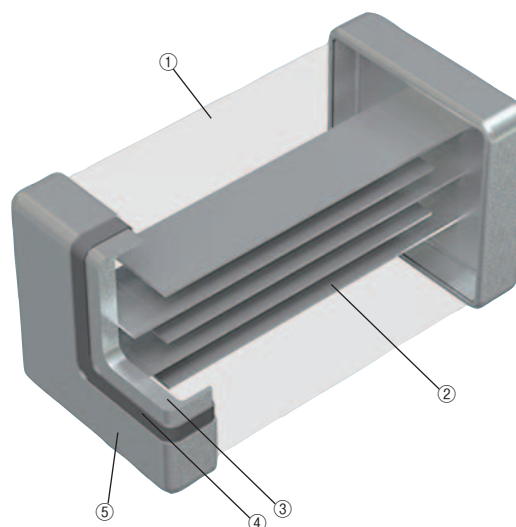
■ EQUIVALENT CIRCUIT OF CHIP VARISTORS



■ CHIP VARISTORS FEATURE

- IEC61000-4-2 LEVEL4 compliant.
- Reliability characteristics evaluated based on AEC-Q200 condition. (Automotive products)
- High ESD withstanding voltage
- Small-sized products are available
- 125°C, 150°C Supported

Fig.1 Internal structure of multilayer chip varistors



No.	Name
(1)	Semiconductor ceramics
(2)	Internal electrode (Pd)
(3)	Ag
(4)	Terminal electrode (Ni)
(5)	Sn

Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

Overview of the AVR/SGNE series

PART NUMBER CONSTRUCTION

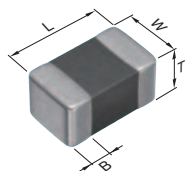
AVRM	1608	C	390	K	T	271	N
Series name	L x W dimensions (mm)	Structure code	Varistor voltage (V)	Varistor voltage tolerance (%)	Packaging style	Capacitance (pF)	Capacitance tolerance (%)
	0402 0.4x0.2	C General structure	390=39x10 ⁰	K ±10	T Taping	271=27x10 ¹	K ±10
	0603 0.6x0.3		6R8 6.8	M ±20	B Bulk	221 220	M ±20
	1005 1.0x0.5		270 27	N ±30		271 270	N ±30
	1608 1.6x0.8		390 39				
	2012 2.0x1.2						

AVR-M	1608	C	270	M	T	AAB
Series name	L x W dimensions (mm)	Structure code	Varistor voltage (V)	Varistor voltage tolerance (%)	Packaging style	Company special symbol
	0603 0.6x0.3	C General structure	270=27x10 ⁰	K ±10	T Taping	
	1005 1.0x0.5	G Conductive paste compatible	080 8	M ±20	B Bulk	
	1608 1.6x0.8		120 12	N ±30		
	2012 2.0x1.2		270 27			

AVRL	10	1A	3R3	F	T	A
Series name	L x W dimensions (mm)	Maximum continuous voltage (V)	Capacitance (pF)	Capacitance tolerance (pF)	Packaging style	Company special symbol
	04 0.4x0.2	1A 10	R50 0.5	F ±1	T Taping	
	06 0.6x0.3	1D 20	1R1 1.1	G ±2	B Bulk	
	10 1.0x0.5	1E 25	3R3 3.3	N ±0.3		
	16 1.6x0.8		6R8 6.8			

AVRH	10	C	270	K	T	150	N	A	8
Series name	L x W dimensions (mm)	Structure code	Varistor voltage (V)	Varistor voltage tolerance (%)	Packaging style	Capacitance (pF)	Capacitance tolerance	ESD voltage amount IEC61000-4-2 (kV)	Operating temperature limit (°C)
	1005 1.0x0.5	C General structure	270=27x10 ⁰	K ±10	T Taping	150=15x10 ⁰	K ±10%	A 25	8 150
			270 27		B Bulk	4R7 4.7	M ±20%	E 8	
			390 39			150 15	N ±30%		
			101 100			500 50	Y ±0.13pF		

SGNE	04	C	080	M	T	150	N	25
Series name	L x W dimensions (mm)	Structure code	Varistor voltage (V)	Varistor voltage tolerance (%)	Packaging style	Capacitance (pF)	Capacitance tolerance	ESD clamping voltage Average voltage (IEC61000-4-2, 8kV)
	04 0.4x0.2	C General structure	080=8x10 ⁰	K ±10	T Taping	150=15x10 ⁰	N ±30%	
	06 0.6x0.3		080 8		B Bulk	6R8 4.7	Y ±0.13pF	
	10 1.0x0.5		270 27			150 15		



Shape symbol (JIS)	L	W	T	B
0402	0.40±0.02	0.20±0.02	0.20±0.02	0.07min.
0603	0.60±0.03	0.30±0.03	0.30±0.03	0.1min.
1005	1.00±0.05	0.50±0.05	0.50±0.05	0.1min.
1608	1.60±0.10	0.80±0.10	0.80±0.10	0.2min.
2012	2.00±0.20	1.25±0.20	0.70±0.20	0.2min.

⚠ Please be sure to request delivery specifications that provide further details on the features and specifications of the products for proper and safe use.
Please note that the contents may change without any prior notice due to reasons such as upgrading.

Chip varistors

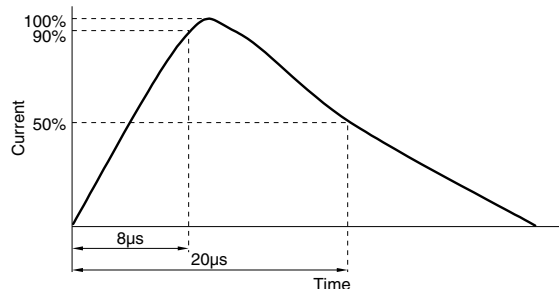
RoHS Directive Compliant Product
Compatible with lead-free solders

Overview of the AVR/SGNE series

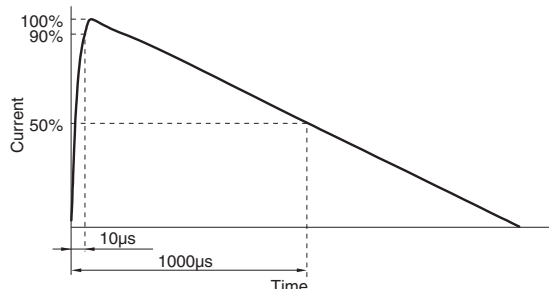
■ TERMINOLOGY

Item	Unit	Description
Varistor voltage (Breakdown voltage)	V _{1mA} (V)	Chip varistor-terminal voltage when DC1mA was flowed
Maximum continuous voltage	V _{dc} (V)	DC voltage that is continuously applied between chip varistor terminals Terminal chip varistors leakage current-value: 50μA max. Voltage appearing across the varistor when a pulse current (8/20μs*1) of specified peak value is applied.
Clamping voltage	V _{cl} (V)	Voltage between terminal chip varistors of the Specified peak current value of the impulse current (8/20μs*1) is applied
Maximum energy	E (Joule)	When applied specified peak impulse current-value current (10/1000μs*2) once, maximum energy that electrical property of chip varistors be not deteriorated
Maximum peak current	I _p (A)	When applied impulse current (8/20μs*1) once, maximum current that electrical property of chip varistors be not deteriorated
Capacitance	C (pF)	Oscillator frequency 1kHz or 1MHz, capacitance between chip varistor-terminal in oscillator voltage 1Vrms

*1 8/20μs test waveform



*2 10/1000μs test waveform



Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

AVR/SGNE series Product characteristics list

■ PRODUCT CHARACTERISTICS LIST

Item	V (1mA) (V)	C1kHz *C1MHz (pF)	Vdc DC (V)	Clamping voltage 8/20μs Vcl (V)	Maximum energy 10/1000μs E (J)	Maximum peak current 8/20μs Ip (A)	Operating temperature range (°C)	IEC61000-4-2 (Contact) 150pF/330Ω	AEC-Q200
AVRL041E1R1NTA	39(31.2 to 46.8)	1.1(0.8 to 1.4)*	25	—	—	—	-40 to +85	4kV (Level2)	
AVRM0402C120MT330N	12(9.6 to 14.4)	33(23.1 to 42.9)	5.5	20(1A)	0.005	1	-40 to +85	8kV (Level4)	
AVRM0402C6R8NT101N	6.8(4.76 to 8.84)	100(70 to 130)	3.5	15(1A)	0.01	4	-40 to +85	8kV (Level4)	
SGNE04C080MT150N25	8(6.4 to 9.6)	15(10.5 to 19.5)	5.5	21(1A)	0.005	1	-40 to +85	8kV (Level4)	
AVRL061E1R1NTA	39(35.0 to 43.0)	1.1(0.8 to 1.4)*	25	—	—	—	-40 to +85	4kV (Level2)	
AVRL061FR50ETA	140(112 to 168)	0.5(0.3 to 0.7)*	30	—	—	—	-40 to +85	4kV (Level2)	
AVRM0603C080MT101N	8(6.4 to 9.6)	100(70 to 130)	5.5	17(1A)	0.01	4	-40 to +85	8kV (Level4)	
AVRM0603C120MT101N	12(9.6 to 14.4)	100(70 to 130)	5.5	20(1A)	0.01	5	-40 to +85	8kV (Level4)	
AVRM0603C120MT150N	12.8(10.0 to 15.6)	15(10.5 to 19.5)	5.5	35(1A)	0.003	1	-40 to +85	8kV (Level4)	
AVR-M0603C120MTAAB	12(9.6 to 14.4)	33(23.1 to 42.9)	7.5	23(1A)	0.01	1	-40 to +85	8kV (Level4)	
AVRM0603C200MT150N	20(16 to 24)	15(10.5 to 19.5)*	12	40(1A)	0.01	1	-40 to +85	8kV (Level4)	
AVRM0603C6R8NT101N	6.8(4.76 to 8.84)	100(70 to 130)	3.5	14(1A)	0.01	10	-40 to +85	8kV (Level4)	
AVRM0603C6R8NT331N	6.8(4.76 to 8.84)	330(231 to 429)	3.5	14(1A)	0.02	16	-40 to +85	8kV (Level4)	
SGNE06C080MT150N25	8(6.4 to 9.6)	15(10.5 to 19.5)	5.5	21(1A)	0.005	1	-40 to +85	8kV (Level4)	
SGNE06C270MT6R8G60	27(21.6 to 32.4)	6.8(4.8 to 8.8)*	15	54(1A)	0.005	1	-40 to +85	8kV (Level4)	
AVRL101A1R1NTA	90(79.6 to 110.4)	1.1(0.8 to 1.4)*	10	—	—	—	-40 to +85	8kV (Level4)	
AVRL101E1R1NTB	39(31.2 to 46.8)	1.1(0.8 to 1.4)*	25	—	—	—	-40 to +85	4kV (Level2)	
AVRL101D3R3FTA	27(21.6 to 32.4)	3.3(2.3 to 4.3)*	20	62(0.5A)	0.01	0.5	-40 to +125	8kV (Level4)	✓
AVRL101D6R8GTA	27(21.6 to 32.4)	6.8(4.8 to 8.8)*	20	58(1A)	0.01	1	-40 to +125	8kV (Level4)	✓
AVR-M1005C080MTAAB	8(6.4 to 9.6)	650(520 to 780)	5.5	14(1A)	0.04	25	-40 to +85	8kV (Level4)	
AVR-M1005C080MTABB	8(6.4 to 9.6)	100(55 to 145)	5.5	15(1A)	0.02	3	-40 to +85	8kV (Level4)	
AVR-M1005C080MTACB	8(6.4 to 9.6)	33(14 to 52)	5.5	19(1A)	0.01	1	-40 to +85	8kV (Level4)	
AVR-M1005C080MTADB	8(6.4 to 9.6)	480(384 to 576)	5.5	14(1A)	0.04	25	-40 to +85	8kV (Level4)	
AVR-M1005C120MTAAB	12(9.6 to 14.4)	130(104 to 156)	7.5	20(1A)	0.05	10	-40 to +85	8kV (Level4)	
AVR-M1005C120MTACC	12(9.6 to 14.4)	460(276 to 644)*	7.5	21(1A)	0.01	24	-40 to +85	8kV (Level4)	
AVR-M1005C180MTAAB	18(14.4 to 21.6)	120(72 to 168)*	11	30(1A)	0.06	16	-40 to +85	8kV (Level4)	
AVRM1005C270KT101N	27(24.0 to 30.0)	100(70 to 130)	19	44(1A)	0.06	4	-40 to +85	8kV (Level4)	
AVR-M1005C270MTAAB	27(21.6 to 32.4)	40(30 to 48)	15	47(1A)	0.04	47	-40 to +85	8kV (Level4)	
AVR-M1005C270MTABB	27(21.6 to 32.4)	15(10.5 to 19.5)	15	49(1A)	0.05	1	-40 to +85	8kV (Level4)	
AVRM1005C6R8NT101N	6.8(4.76 to 8.84)	100(70 to 130)	3.5	14(1A)	0.02	10	-40 to +85	8kV (Level4)	
AVRM1005C6R8NT331N	6.8(4.76 to 8.84)	330(231 to 429)	3.5	15(1A)	0.008	24	-40 to +85	8kV (Level4)	
SGNE10C080MT150N28	8(6.4 to 9.6)	15(10.5 to 19.5)	5.5	21V(1A)	0.01	19	-40 to +85	8kV (Level4)	
AVRH10C270KT150NA8	27(24.0 to 30.0)	15(10.5 to 19.5)	19	52(2A)	0.02	2	-55 to +150	25kV	✓
AVRH10C270KT350NA8	27(24.0 to 30.0)	35(24.5 to 45.5)	19	52(2A)	0.02	8	-55 to +150	25kV	✓
AVRH10C390KT500NA8	39(35.0 to 43.0)	50(35 to 65)	28	72(2A)	0.02	15	-55 to +150	25kV	✓
AVRH10C101KT4R7FA8	100(90 to 110)	4.7(3.7 to 5.7)*	70	190(1A)	0.03	1	-55 to +150	25kV	✓
AVRH10C101KT1R1NE8	110(100 to 120)	1.1(0.8 to 1.4)*	70	190 (0.3A)	0.01	0.3	-55 to +150	8kV (Level4)	✓
AVRH10C221KT1R5YA8	220 (198 to 242)	1.5(1.37 to 1.63)*	70	400 (0.5A)	0.01	0.5	-55 to +150	25kV	
AVRL161A1R1NTA	90(79.6 to 110.4)	1.1(0.8 to 1.4)*	10	—	—	—	-40 to +85	8kV (Level4)	
AVRL161A1R1NTB	39(31.2 to 46.8)	1.1(0.8 to 1.4)*	10	—	—	—	-40 to +85	4kV (Level2)	
AVRL161D3R3FTA	27(21.6 to 32.4)	3.3(2.3 to 4.3)*	20	62(0.5A)	0.01	0.5	-40 to +125	8kV (Level4)	✓
AVRL161D6R8GTA	27(21.6 to 32.4)	6.8(4.8 to 8.8)*	20	58(1A)	0.01	1	-40 to +125	8kV (Level4)	✓
AVR-M1608C080MTAAB	8(6.4 to 9.6)	650(520 to 780)	5.5	15(2A)	0.09	30	-40 to +85	8kV (Level4)	
AVR-M1608C120MT2AB	12(9.6 to 14.4)	400(320 to 480)	7.5	20(2A)	0.06	15	-40 to +85	8kV (Level4)	
AVR-M1608C120MT6AB	12(9.6 to 14.4)	1050(840 to 1260)	7.5	20(2A)	0.09	50	-40 to +85	8kV (Level4)	
AVR-M1608C180MT6AB	18(14.4 to 21.6)	600(480 to 720)	11	30(2A)	0.10	30	-40 to +85	8kV (Level4)	
AVR-M1608C220KT2AB	22(19.8 to 24.2)	210(147 to 273)	16	37(2A)	0.03	10	-40 to +125	25kV	✓
AVR-M1608C220KT6AB	22(19.8 to 24.2)	560(392 to 728)	16	34(2A)	0.10	30	-40 to +125	25kV	✓
AVR-M1608C270MTABB	27(21.6 to 32.4)	15(10.5 to 19.5)	17	52(2A)	0.05	2	-55 to +150	25kV	✓
AVR-M1608C270MTAAB	27(21.6 to 32.4)	30(21 to 39)	17	52(2A)	0.05	2	-55 to +150	25kV	✓
AVR-M1608C270KTACB	27(24.0 to 30.0)	60(42 to 78)	19	54(2A)	0.05	10	-55 to +150	25kV	✓
AVRM1608C270KT800M	27(24.0 to 30.0)	80(64 to 96)	19	53(2A)	0.02	28	-55 to +150	25kV	✓
AVR-M1608C270KT2AB	27(24.0 to 30.0)	160(112 to 208)	19	42(2A)	0.10	20	-55 to +150	25kV	✓
AVRM1608C270KT221M	27(24.0 to 30.0)	220(176 to 264)	19	52(2A)	0.10	40	-55 to +150	25kV	✓
AVR-M1608C270KT6AB	27(24.0 to 30.0)	430(301 to 559)	19	42(2A)	0.10	48	-55 to +150	25kV	✓
AVR-M1608G270KT6AB	27(24.0 to 30.0)	430(301 to 559)	19	42(2A)	0.10	48	-55 to +150	25kV	✓
AVRM1608C390KT271N	39(35.0 to 43.0)	270(189 to 351)	28	69(2A)	0.10	78	-55 to +150	25kV	✓
AVRM1608C560KT101M	56(50.4 to 61.6)	100(80 to 120)	40	113(2A)	0.10	60	-55 to +150	25kV	✓
AVRM1608C720KT750M	72(64.8 to 79.2)	75(60 to 90)	53	135(2A)	0.10	40	-55 to +150	25kV	✓
AVR-M2012C120MT6AB	12(9.6 to 14.4)	1000(550 to 1450)	7.5	20(5A)	0.20	60	-40 to +85	8kV (Level4)	
AVR-M2012C220KT6AB	22(19.8 to 24.2)	800(560 to 1040)	16	38(5A)	0.30	100	-40 to +125	25kV	✓
AVRM2012C330KT801N	33(29.7 to 36.3)	800(560 to 1040)	24	59(5A)	0.50	240	-55 to +150	25kV	✓
AVR-M2012C390KT6AB	39(35.0 to 43.0)	430(387 to 483)	28	62(5A)	0.30	100	-55 to +150	25kV	✓
AVBM2012C560KT251M	56(50.4 to 61.6)	250(200 to 300)	40	113(5A)	0.30	150	-55 to +150	25kV	✓
AVRM2012C720KT201M	72(64.8 to 79.2)	200(160 to 240)	53	142(5A)	0.30	100	-55 to +150	25kV	✓

⚠ Please be sure to request delivery specifications that provide further details on the features and specifications of the products for proper and safe use.
Please note that the contents may change without any prior notice due to reasons such as upgrading.

Chip varistors

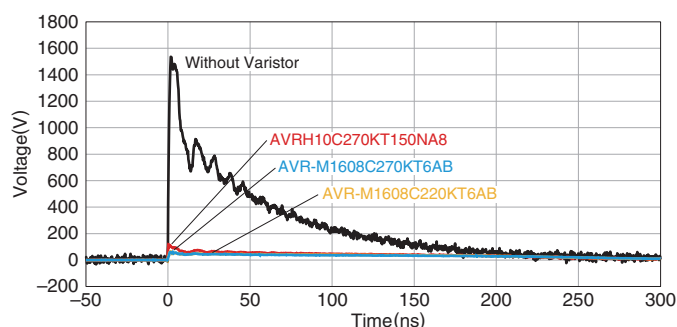
RoHS Directive Compliant Product
Compatible with lead-free solders

AVR/SGNE series

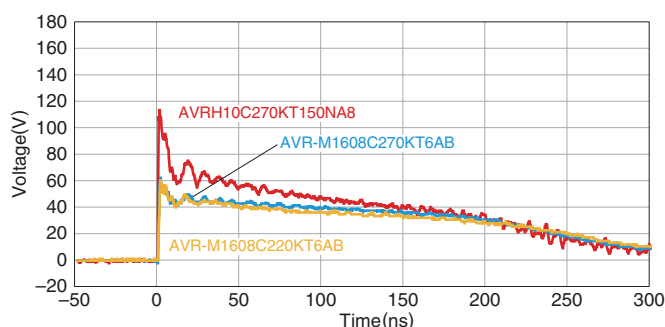
Electrostatic absorption characteristics

DISCHARGE VOLTAGE WAVEFORM (EXAMPLE)

WITHOUT VARISTOR, WAVEFORM AT VARISTOR INSTALLATION



WAVEFORM AT VARISTOR INSTALLATION

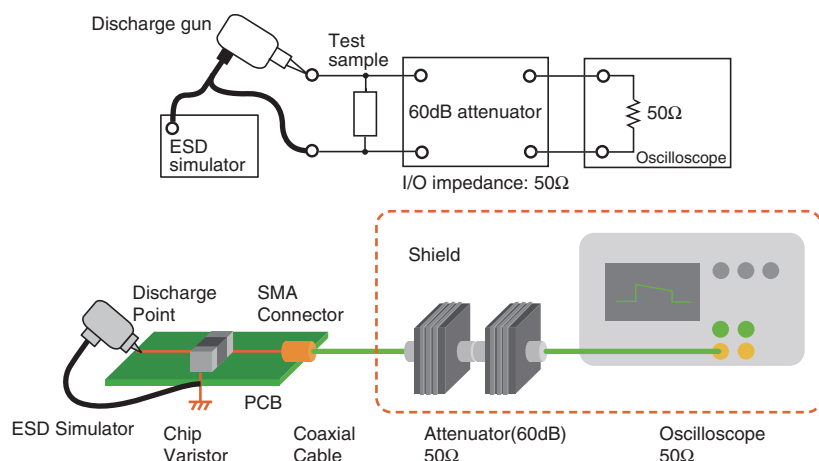


Test conditions

150pF/330Ω (IEC61000-4-2)

Contact discharge, Charged voltage 8kV

TEST CIRCUIT DIAGRAM



Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

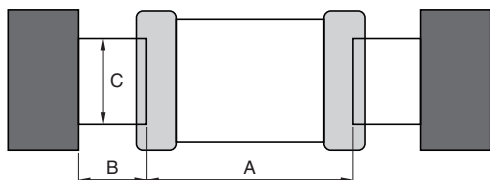
Attention on a circuit board design

Board design

When attached to chip varistors, amount of silver used (fillet size) has direct impact on chip varistors after mounting. Thus, sufficient consideration is necessary.

Set of land dimensions

(1) As the stress rises in the chip varistors owing to the increase in silver, breakage and cracks will occur. Cause including crack, as caution on board land design, configure the shape and dimensions so that the amount of silver is appropriate. If you installed 2 or more parts in the Common Land, separated by a solder resist and special land of each component.



Dimensions shape	Symbol		
	A	B	C
0402	0.20 Nom.	0.15 to 0.21	0.18 to 0.20
0603	0.25 to 0.35	0.20 to 0.30	0.25 to 0.35
1005	0.30 to 0.50	0.35 to 0.45	0.40 to 0.60
1608	0.60 to 0.80	0.60 to 0.80	0.60 to 0.80
2012	0.90 to 1.20	0.70 to 0.90	0.90 to 1.20

(2) When peak levels panning-at soldering is excessive, by solder contraction stress, mechanical-thermal stress causes a Yasuku chip crack. In addition, when the peak level is underestimated, terminal electrode fixed strength is insufficient. This causes chip dropouts and may affect circuit reliability. Representative example of the panning of peak levels is shown in the following.

Recommended silver dose

Solder volume overload		Solder stress is increased, and it is easy for a crack to form.
Decent solder volume		
Solder volume deficit		Fixed strength is weak, and there is connection a problem and risk of loss.

Case and suggested protocol want to avoid

Example	Cases to avoid	Improvement example (land division)
Lead wire and land of part discrete doubles up		
Arrangements in the vicinity		
Arrangements of chip component's companion		

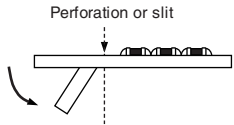
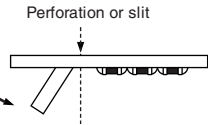
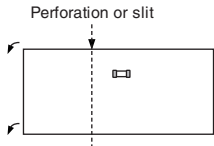
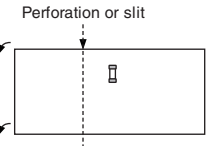
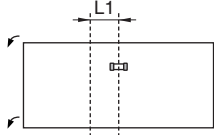
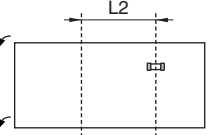
Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

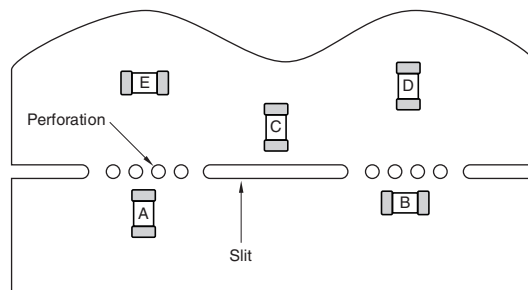
Attention on a circuit board design

Arrangements of components

(1) I was based on camber of substrate and suggested protocol of chip varistors arrangement, as stress does not join to the utmost is shown in following.

	Substrate for flexural stress Adverse events	Substrate for flexural stress Good example
Direction of surface solder	 Solder the mountain fold as a top.	 Solder the mountain fold as a bottom. [Please review the italicized portion, as I am unsure what you mean to convey here.]
Chip arrangements (direction)	 Mounted vertically to the perforation and slit.	 Mounted horizontally to the perforation and slit.
Distance from perforation and slit portion	 ($L1 < L2$) Close location is disadvantageous of perforation and slit.	 ($L1 < L2$) It is an advantage so distant location away places the perforation and slit.

(2) In payment near by board, depending on mount position of chip varistors, as mechanical stress varies, please refer to the following diagram.



The order of $A > B = C > D > E$ eases the stress.

Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

Local precautions

Application to board

Mounting head pressure

Under suction nozzle if dead point too, during implementation, excessive force joins of chip varistors low, as cause causes of crack, please use with reference to something about following.

- 1) Being set to top surface of substrate so that under suction nozzle as for dead center, substrate does not bend back, and adjust, please.
- 2) Nozzle pressure at implementation is 0.1 to 0.3N in static load, please.
- 3) Substrate fixes up back surface of substrate with support pin in impact of suction nozzle to wely deflection to the utmost, and substrate hold deflection, please. A representative example is shown in the following.

Cases to avoid	Recommended case
Single-sided mounting	
Double-sided mounting	

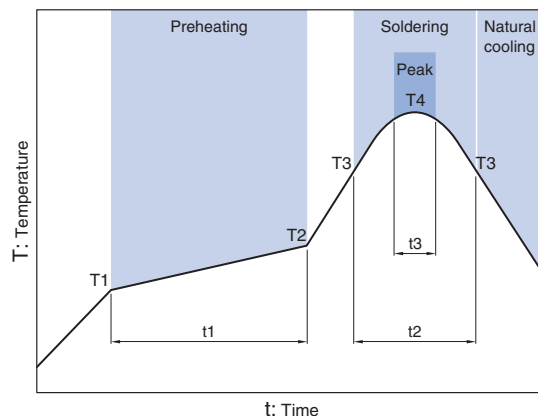
Mechanical shock that, if positioning your nail to wear, ragged edge of positionings, participates in chip varistors are locally, and chip varistors, as there is possibility of crack generated, cut the closed positioning, and maintenance and inspection, and, exchange of manage dimensions and position nail periodically, please.

Soldering

Significant impact is possible on the performance of chip varistors, flux checks something about follow, please use.

- (1) Flux uses one with 0.1wt % (Cl conversion) or less halide substance contains amounts, please. In addition, do not do this with strongly acidic objects.
- Flux during is soldered (2) Chip varistors is applied the smalleset amount necessary, please.
- (3) If Used soluble flux, perform thorough wash particularly, please.

Reflow temperature profile



Item	Specification	
	For eutectic mixture solder	Use of lead-free solder
Preheating temperature	160 to 180°C	150 to 180°C
Solder melting temperature	200°C	230°C
Maximum temperature	240°C max.	260°C max.
Preheating time	100s max.	120s max.
Time to reach higher than the solder melting temperature	30s max.	40s max.
number of possible reflow cycles	2 max.	2 max.

Soldering iron

The tip temperature and also by (1) types of soldering irons, the size of the substrate, and the geometry of the land pattern. Being earlier, but when as there is possibility that crack occurs in the heat anderson impactation, point soldering iron temperature is high, please do solder work within the following conditions.

Temperature of iron tips (°C)	Wattage (W)	Pallet point shape (mm)	Soldering time (Second)	Frequency
350max.	30max.	ø3.0max.	5 max.	Within each terminal once (Within total of twice)

Direct iron tip is in contact with the (2) chip varistors body, and the strain owing to thermal shock in particular grows even if a crack is generated. Therefore, please do not touch it directly to the terminal electrodes.

Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

Attention after implementation

Cleaning

- (1) If cleaning liquid is inappropriate, residues and other foreign body of fluxes builds up on chip varistors, and can degrade the performance of chip varistors (particularly the insulation resistance).
- (2) Wash conditions may compromise performance of chip varistors if they are improper (wash due, wash excess).

2-1) For wash due

- (a) By substance of a system in flux residue halide, metal including terminal electrodes may experience corrosion.
- (b) Substance of a system in flux residue halide builds up on chip varistors, and reduces the insulation resistance.
- (c) Soluble flux makes comparisons of colophony series flux, and there is event with trends of significant (1) and (2).

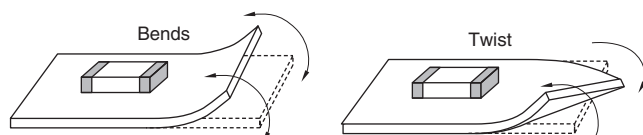
2-2) For excess wash

- (1) Owing to lavage, chip varistors deteriorates, and reduces performance of chip varistors.
- (2) In ultrasonography, when output is passed, substrate resonates size, and crack occurs in body and sprang of chip varistors in vibration of substrate. Since this may reduce the strength of the terminal electrode, please note the following conditions. [Please review the italicized portion, as I am unsure what you mean to convey here.]
 - Ultrasound output
 - Ultrasonic frequency
 - Ultrasound cleaning time

2-3) Concentration including halogen that when cleaning liquid to pollution, when you released is higher, and may cause similar of results into wash due.

Substrate handling after component mounting

- (1) When substrate is divided, a flexible so that show in following diagram to substrate, and is given by stress including twist, as there is possibility that crack occurs of chip varistors, please check that stress is within acceptable limits.

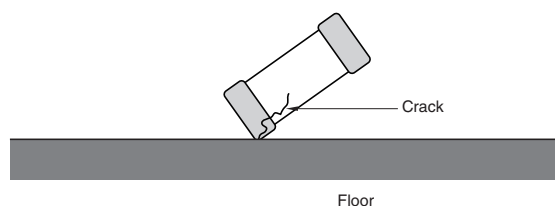


- (2) During each substrate operational check, push pressure with contact failure of check pin of boards checkers of check pin may be toned up to be prevented. As substrate is bent under loading, chip varistors is broken owing to stress. There is also the possibility that solder on the terminal electrode will peel off. Follow the diagram for reference, and check that the substrate bends, please.

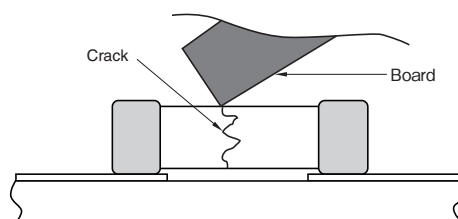
Item	Cases to avoid	Recommended case
Substrate sags		

Single-part component handling

To drop impact, as there is possibility that breakage and crack is entered, do not chip varistors that (1) chip varistors falls.



- (2) At stacking storage after implementation and treatment of substrate, corner of boards is regarded as chip varistors. Please be careful, as there is the possibility that breakage and cracks will occur on impact.

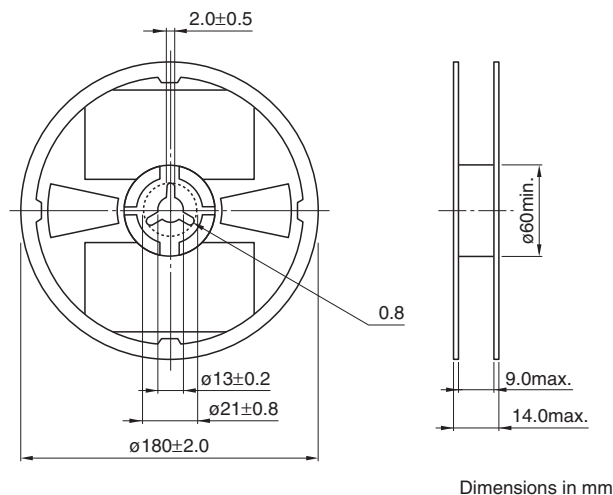


Chip varistors

RoHS Directive Compliant Product
Compatible with lead-free solders

Packaging style

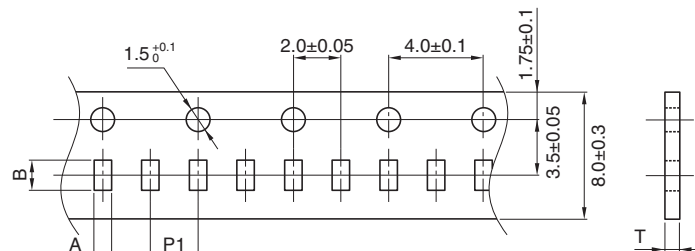
REEL DIMENSIONS



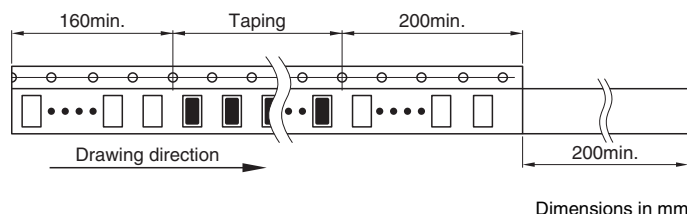
PACKAGE QUANTITY / INDIVIDUAL WEIGHT

Type	Package quantity (pieces/reel)	Individual weight (mg)
AVRM0402/AVRL04/SGNE04	20,000	0.1
AVRM0603/AVR-M0603/AVRL06/ SGNE06	15,000	0.2
AVRM1005/AVR-M1005/AVRL10/ AVRH10	10,000	1.2
AVRM1608/AVR-M1608/AVRL16	4,000	5
AVRM2012/AVR-M2012	2,000	13

TAPE DIMENSIONS



Type	A	B	P1	T
0402	0.26±0.04	0.46±0.04	2.0±0.05	0.40max.
0603	0.38±0.05	0.68±0.05	2.0±0.05	0.45max.
1005	0.65+0.05/-0.1	1.15+0.05/-0.1	2.0±0.05	0.65max.
1608	1.1±0.2	1.9±0.2	4.0±0.1	1.1max.
2012	1.5±0.2	2.3±0.2	4.0±0.1	1.1max.



REMINDERS FOR USING THESE PRODUCTS

Before using these products, be sure to request the delivery specifications.

SAFETY REMINDERS

Please pay sufficient attention to the warnings for safe designing when using this products.

REMINDERS

- Please pay careful attention to the precautions and follow safe designing practices when using these products.
- Please observe the following precautions in order to avoid problems with chip varistors such as characteristic degradation and element destruction
 - Please store these products in an environment with a temperature of 5 to 40°C and humidity level of 20 to 70%RH, and use them within six months.
 - Poor storage conditions may lead to the deterioration of the solderability of the edge electrodes, so please be careful to avoid contact with humidity, dew condensation, dust, toxic gas (hydrogen, hydrogen sulfide, sulfurous acid, chlorine, ammonia, etc.), direct sunlight, and so on.
 - Please do not use products that have been dropped or detached when mounting.
 - Please solder with the reflow soldering method, and not the flow (dip) soldering method.
- Please observe the following precautions to avoid problems with varistors such as characteristic degradation and element destruction, which ultimately lead to the generation of heat and smoke with the elements.
 - Do not use in locations where the temperatures exceed the operating temperature range such as under direct sunlight or near sources of heat.
 - Do not use in locations where there are high levels of humidity such as under direct exposure to weather and areas where steam is released.
 - Do not use in locations such as dusty areas, high-saline environments, places where the atmosphere is contaminated with corrosive gas, etc.
 - Avoid powerful vibrations, impact (such as by dropping), pressure, etc. that may lead to splitting in the products.
 - Do not use with a voltage that exceeds the maximum allowable circuit voltage.**
 - When resin coating (including modular) a varistor, do not use a resin that will cause deterioration of the varistor. Be sure never to use resin that generates hydrogen as palladium is used for the inner electrode.
 - Avoid attachment near combustible materials.
- Please contact our sales offices when considering the use of the products listed on this catalog for applications, whose performance and/or quality require a more stringent level of safety or reliability, or whose failure, malfunction or trouble could cause serious damage to society, person or property ('specific uses' such as automobiles, airplanes, medical instruments, nuclear devices, etc.) as well as when considering the use for applications that exceed the range and conditions of this catalog.
 - Please also contact us when using these products for automotive applications.
- As range of catalog, conditions are transcended, or for damage that generated by was used in application specific, etc, accept no the responsibility, wish.
- Please take appropriate measures such as acquiring protective circuits and devices that meet the uses, applications, and conditions of the instruments and keeping backup circuits.